INTEGRATED

THIN-FILM COATING

OPTO-ELECTRONIC SOLUTIONS





SOLUTIONS



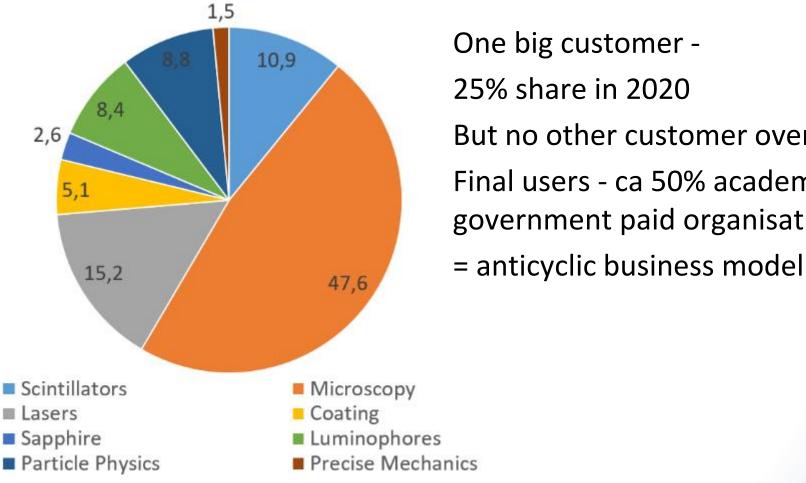




PRECISSION MECHANICS, OPTICS AND SAPPHIRE

Business Areas





One big customer -25% share in 2020 But no other customer over 10% Final users - ca 50% academia and government paid organisations

PRODUCTION PORTFOLIO

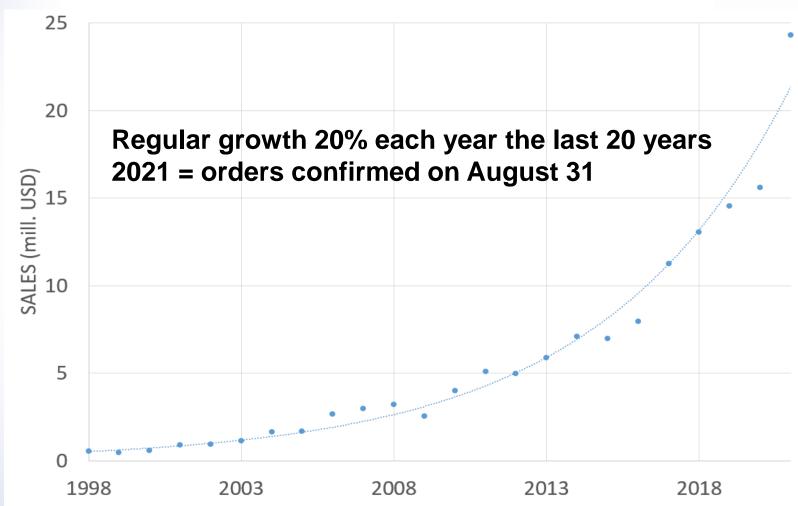
- Global No. 1 supplier of detection units for electron microscopy
- The largest European manufacturer of laser rods
- Leader in single-crystal phosphors for high power LED/LD
- Very strong in radiation detectors





Sales





MANUFACTURING







MANUFACTURING



MANUFACTURING



CRYTUR IN-HOUSE SEM

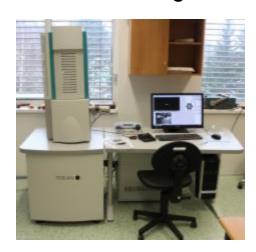
2009 Tesla/Tescan Proxima



W-filament

Production vacuum test chamber
SE, CL, BSE

2012 Tescan Vega



W-filament

Production testing SEM SE, CL, BSE, EDS

2019 TFS Quattro



FEG

R&D+Production SEM Low-vac, Beam deceleration

SE, CL, BSE, EDS, + low-vac, ESEM detectors

CRYTUR KEY COMPETENCE

INTEGRATED TECHNOLOGIES



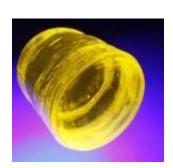
UNDER ONE ROOF

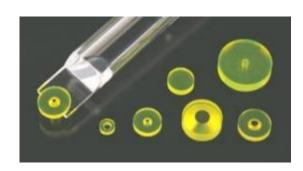
CRYSTAL GROWTH BROAD COMPONENT MANUFACTURING

COATING

CLEAN-ROOM ASSEMBLY SOPHISTICATED CHARACTERISATION TECHNIQUES







SINGLE CRYSTAL SCINTILLATOR



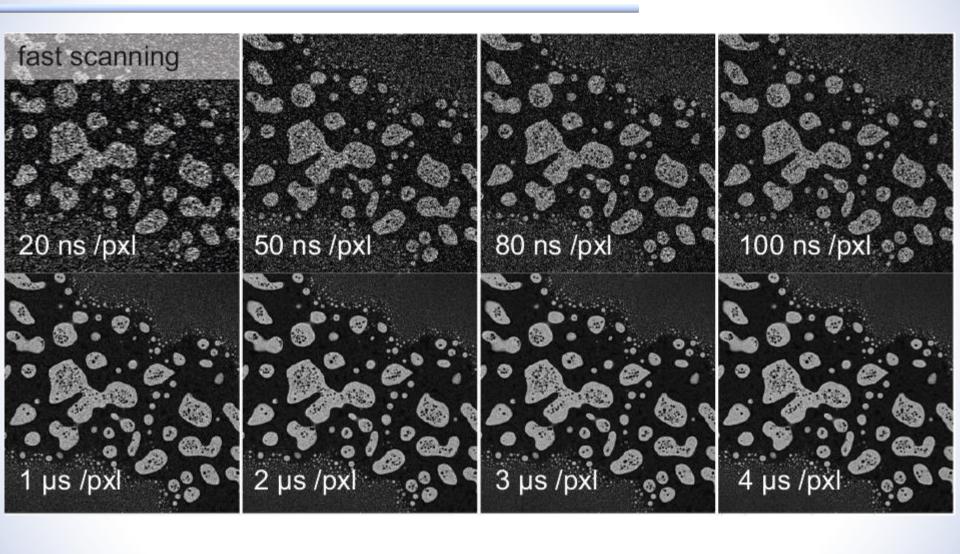
YAG:Ce BSE scintillators



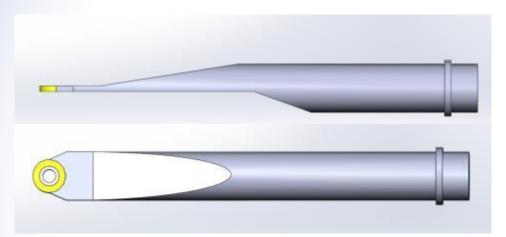
 $YAIO_3:Ce$ $Y_3AI_5O_{12}:Ce$

	YAG:Ce	YAP:Ce	CRY18
Density (g/cm³)	4.57	5.37	4.50
Hardness (Mho)	8.5	8.6	5.8
Crystal structure	cubic	rhombic	monoclinic
Hygroscopic	no	no	no
Refraction index	1.82	1.95	1.79
Wavelength maximum (nm)	550	370	425
Decay time (ns)	70	25	40
Photon yield (photons/keV)	35	25	30
Spectral matching to bialcali PMT –	6	20	21
integral quantum efficiency (%)			

FAST BSE SCANNING



HISTORY

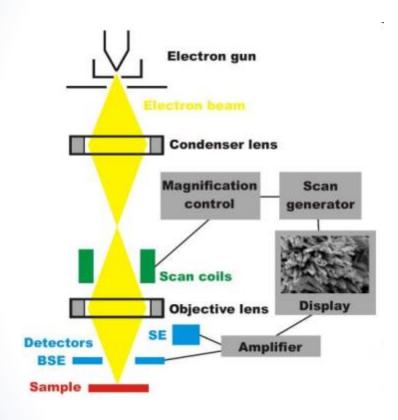


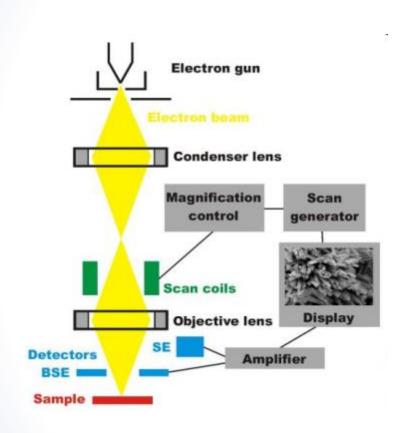


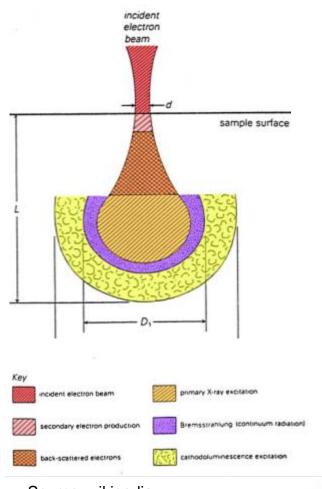
Rudolf Autrata (*1933 - *2006)

- inventor of the Autrata YAG detector of backscattered electrons
- key person of the Institute of Scientific Instruments of the Academy of Sciences of the Czech Rep. in Brno, where he worked his whole life

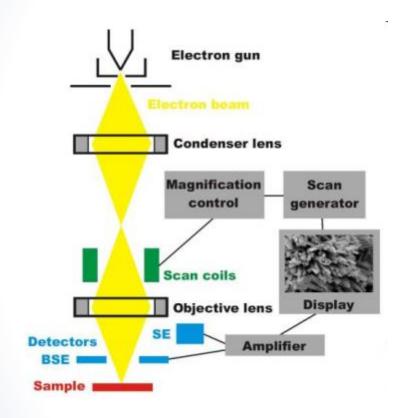
R. Autrata, P. Schauer, Jo. Kvapil and Ji. Kvapil, A single crystal of YAG – new fast scintillator in SEM, J. Phys. E, 11, 707-708, (1978)

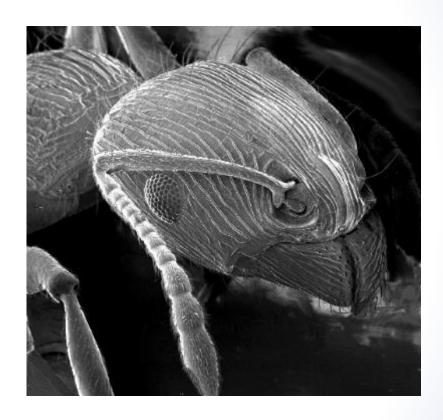


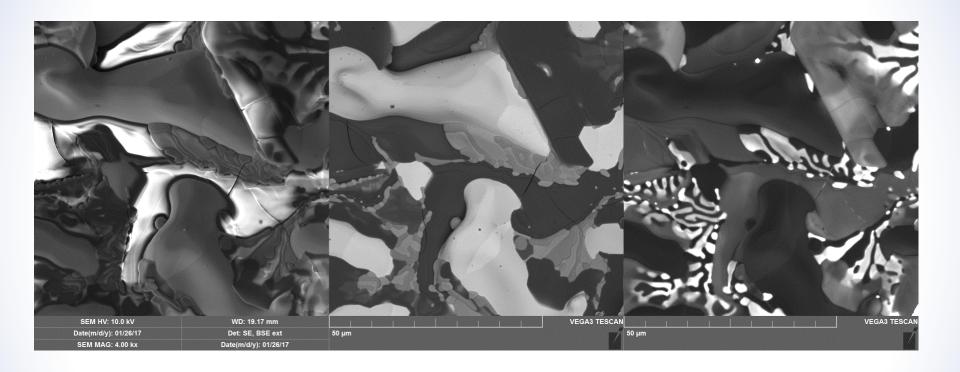


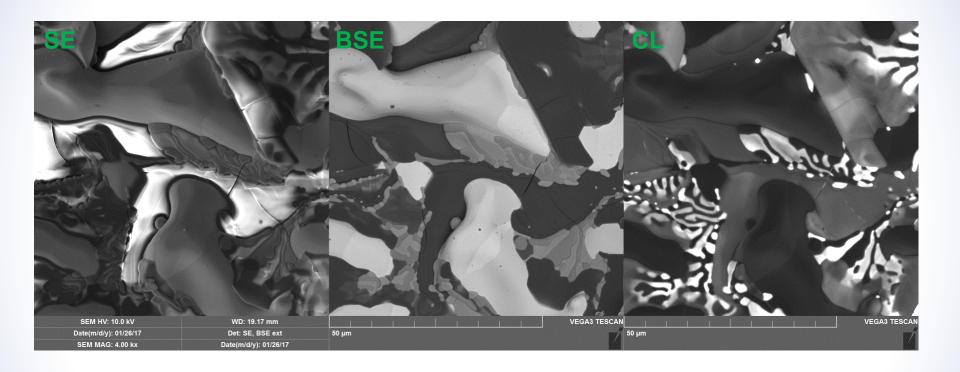


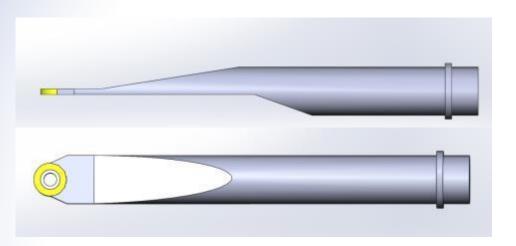
Source: wikipedia







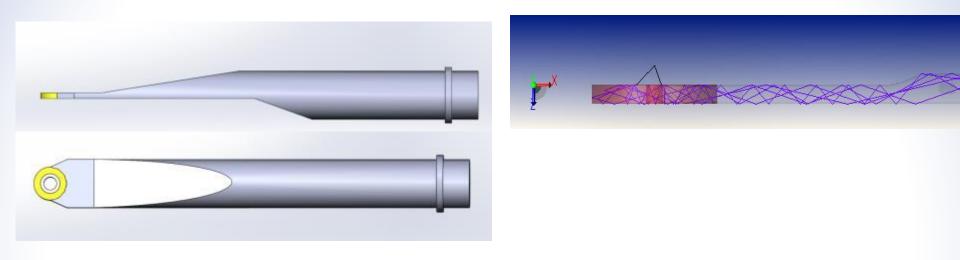




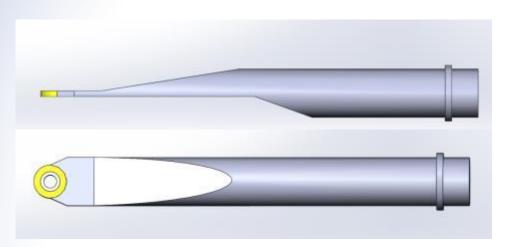
Ligth-guide: PMMA or Quartz glass

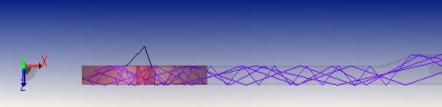
Annular Scintillator

Conventional BSE collection geometry: concentric



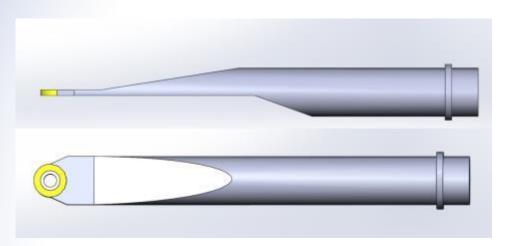
Conventional BSE collection geometry: concentric





25-35% photons reach PMT

- Conventional BSE collection geometry: concentric
- Quest for maximazing photon transport from the Scintillator towards the PMT



30-40% photons reach PMT

- > Concentric scintillation detector
- Quest for maximazing photon transport from Scintillator towards the PMT
- Quest to drill and polish perfect circular hole and to evaporate a conductive coating into it
- Quest for circularity/perpendicularity in case of beam deceleration

Hole diameter of 300µm



- Conventional SE collection geometry: side geometry, but concentric also with more complex e-beam
- Powder scintillator more efficient (P47) for side geometry

Why not a direct detection by some form of p-n junction and amplifier?

Photon yield of YAG:Ce, YAP:Ce, CRY18 vary around 20-30photons/keV

- Why not a direct detection by some form of p-n junction and amplifier?
- Energy conversion of e⁻ to photons in scintillator only approx 5% isation, diffusion, trapping, luminescence

Photon yield of YAG:Ce, YAP:Ce, CRY18 vary around 20-30photons/keV

- Why not a direct detection by some form of p-n junction and amplifier?
- Energy conversion of e⁻ to photons in scintillator only approx 5% isation, diffusion, trapping,
- Optical losses: most of photons get lost on their way to the PMT Reflection, absortion, scattering

Photon yield of YAG:Ce, YAP:Ce, CRY18 vary around 20-30photons/keV

- Why not a direct detection by some form of p-n junction and amplifier?
- Energy conversion of e⁻ to photons in scintillator only approx 5% lisation, diffusion, trapping,
- Optical losses: most of photons get lost on their way to the PMT Reflection, absortion, scattering
- Far less than 1% of absorbed energy gets amplified by the PMT!

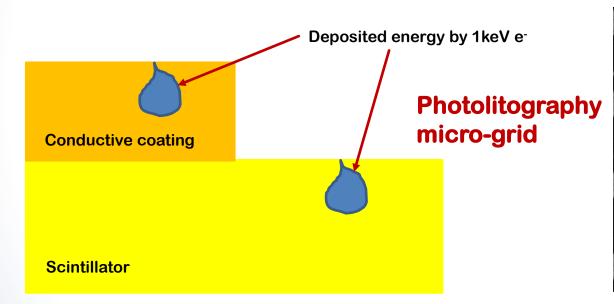
PMT photocathode efficiency

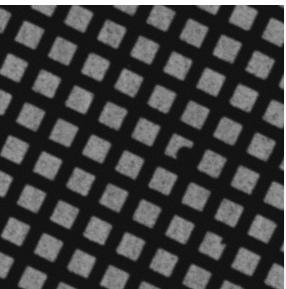
Why not a direct detection by some form of p-n junction and amplifier?

- Fortunately for CRYTUR, the decisive arguments are
 - For Poisson statistics matters whether each e- is detected
 - S/N at all scanning speeds (thanks to PMT)
 - life-time of crystal itself (YAG vs Silicon)
 - optical decoupling from el-mag fields

1pA x 1kev 30nA x 30keV 10⁶ x change of detector gain required

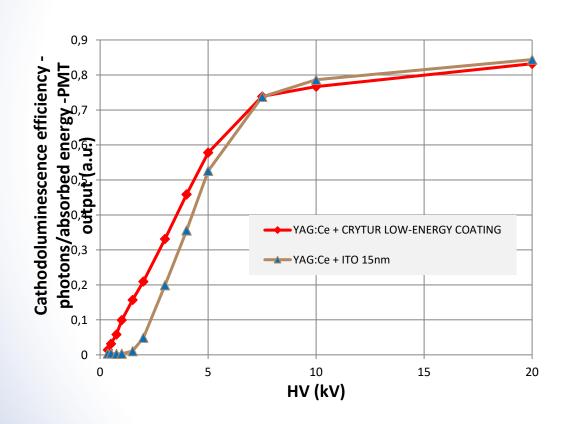
- CRYTUR low-energy coating® sensitive down to 200eV
- Penetration depths down to units of nm

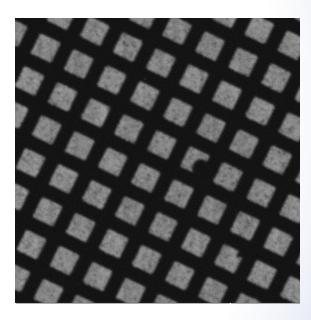




Cathodoluminescence @0.2keV

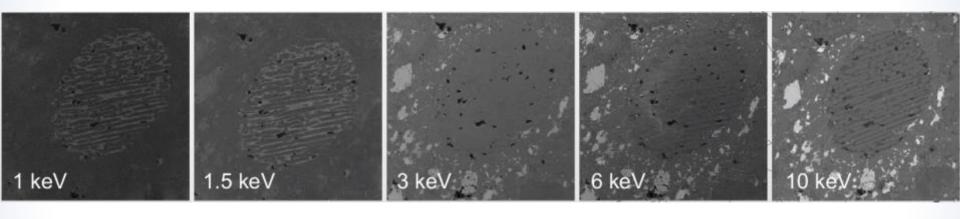
Side view





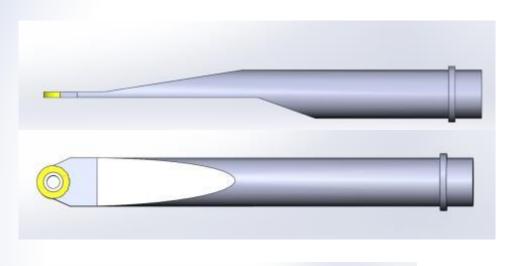
Cathodoluminescence @0.2keV

LOW-ENERGY BSE



Evolution of BSE contrast with increasing landing energy.
Sample: Chondrules and metal flakes in Ghubara Meteorite, provided by Institute of Geology CAS/

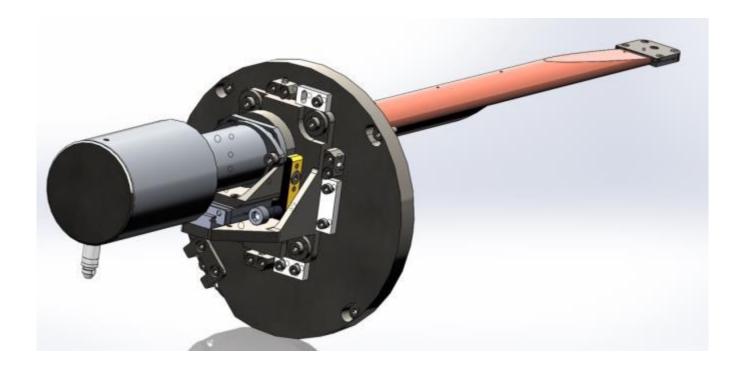
GENERIC BSE DESIGN



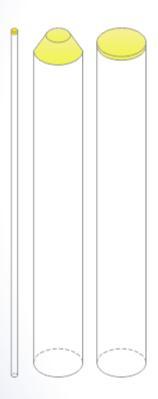




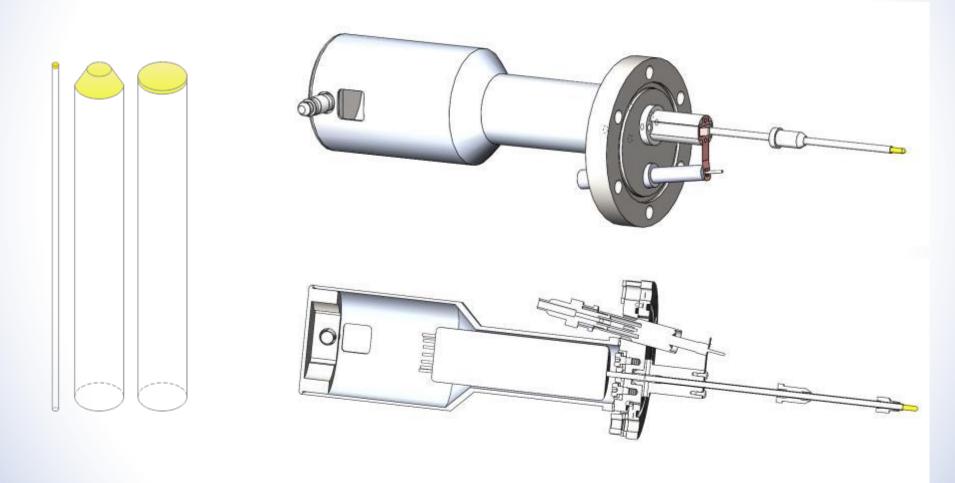
OEM BSE DESIGN



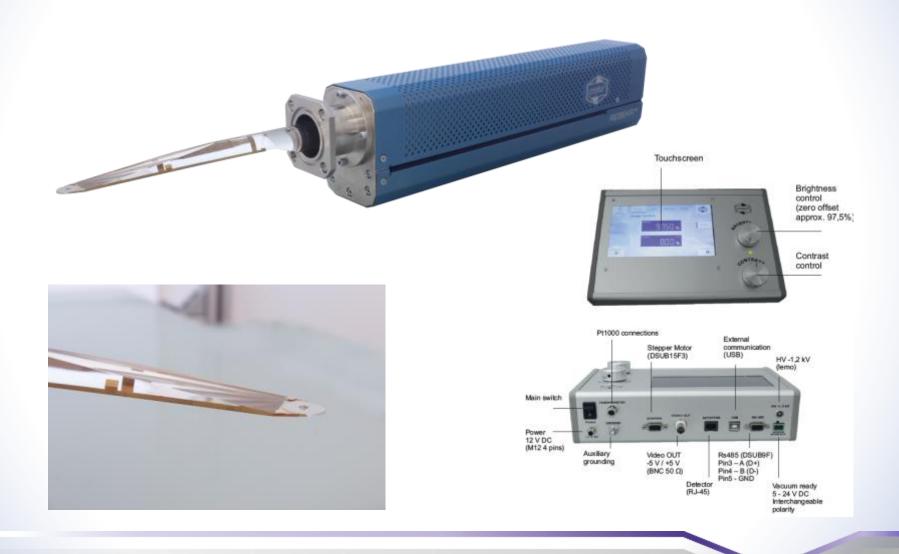
GENERIC SE DESIGN

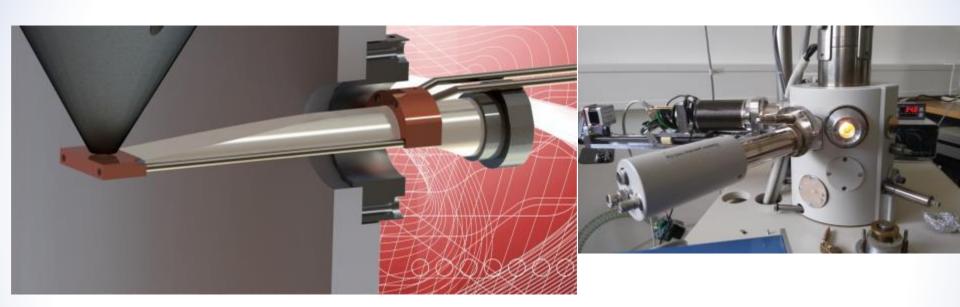


GENERIC SE DESIGN



REBEKA BSE SYSTEM





- Motorized scintillator BSE detector for ultimate S/N and ease of use
- Sample temperature up to 1000C
- Passive cooling using heat-sink and heat-pipes robust and maintenance-free
- Unique optical shielding against IR and VIS light generated by black-body radiation
- Commercial availability since mid-2018

Received: 6 April 2020

Revised: 16 September 2020

Accepted: 10 November 2020

DOI: 10.1111/jmi.12979

ORIGINAL ARTICLE





Evaluation and application of a new scintillator-based heat-resistant back-scattered electron detector during heat treatment in the scanning electron microscope

R. Podor ¹ 0	J. Mendonça ^{1,2}	ļ	J. Lautru ¹	H. P. Brau ¹ D. Nogues ²	
A. Candeias ²	P. Horodysky ³	1	A. Kolouch ³	M. Barreau ⁴ X. Carrier ⁴	
N. Ramenatte ⁵	S. Mathieu ⁵	1	M. Vilasi ⁵		

Correspondence

Renaud Podor, ICSM, Univ Montpellier, CEA, CNRS, ENSCM, 5257 Site de Marcoule, Bàtiment 426 BP 17171, F-30207 Bagnols sur Cèze Cedex, France. Email: Renaud.podor@cea.fr

Funding information

Région Occitanie, Grant/Award Number: Readynov Furna SEM Project

Abstract

A new high-temperature detector dedicated to the collection of backscattered electrons is used in combination with heating stages up to 1050°C, in high-vacuum and low-vacuum modes in order to evaluate its possibilities through signal-to-noise ration measurements and different applications. Four examples of material transformations occurring at high temperature are herein reported: grain growth during annealing of a rolled platinum foil, recrystallisation of a multiphased alloy, oxidation of a Ni-based alloy and complex phase transformations occurring during the annealing of an Al-Si coated boron steel. The detector could be potentially adapted to any type of SEM and it offers good opportunities to perform high-temperature experiments in various atmospheres.

KEVWORDS

backscattered electrons, high temperature, in situ, scanning electron microscopy, VP-SEM

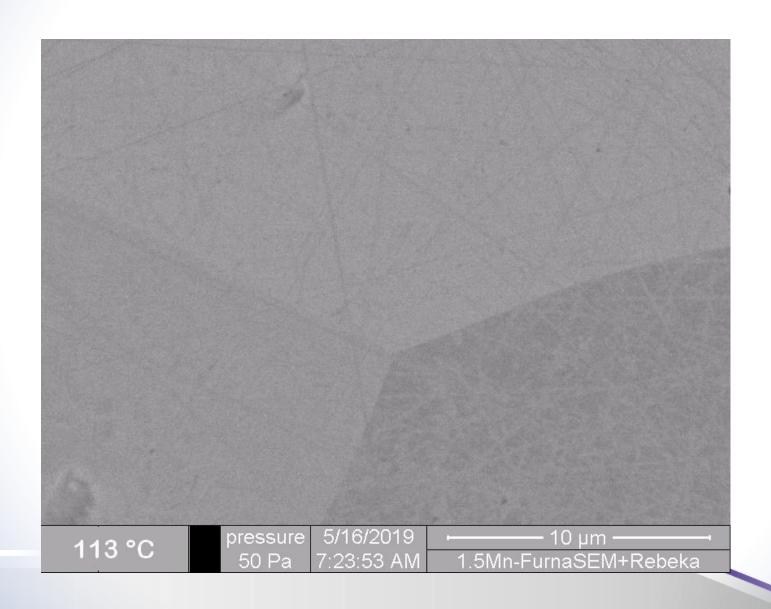
¹ ICSM, Univ Montpellier, CNRS, ENSCM, CEA, Bagnols sur Cèze, France

² NewTEC Scientific, Nimes, France

³ CRYTUR, spol. s.r.o., Czech Republic

⁴ Laboratoire de Réactivité de Surface, CNRS, Sorbonne Université, Paris, France

⁵ CNRS, IJL, Université de Lorraine, Nancy, France



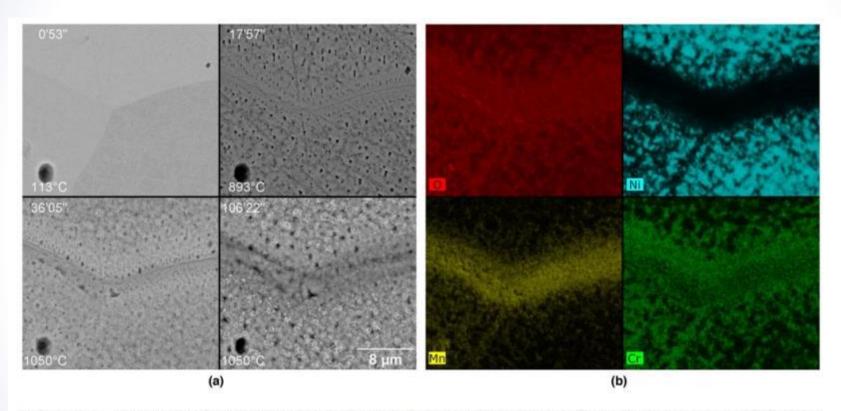


FIGURE 7 (a) High-magnification images of the oxidation of a Ni-25Cr-1.5Mn alloy in 50 Pa air up to 1050° C. (b) X-ray quantitative maps [Ni (L α line), Mn (L α line), Cr (L α line) and O (K α line)] recorded after sample cooling to room temperature on the region of interest observed at 1050° C, t = 106'22'', ($E_0 = 8 \text{ kV}$)

Projects for Grant Agencies

- TA01010164 POKROČILÉ TECHNIKY DETEKCE IONIZUJÍCÍHO ZÁŘENÍ (2011-2014, TA0/TA), CRYTUR+ FJFI ČVUT
- TE01020118 *ELEKTRONOVÁ MIKROSKOPIE* (2012-2019, TA0/TE), 7 partnerů
- H2020-EU.2.1.1.7, ECSEL Joint Undertaking *TAKEMI5* (2017-2019), 26 partnerů
- FV30271 SCINTILAČNÍ DETEKTORY PRO SPECIÁLNÍ POUŽITÍ V SEM (2018-2021, MPO/FV), CRYTUR+ÚPT AVČR
- TN01000008 CENTRUM ELEKTRONOVÉ A FOTONOVÉ OPTIKY (2018-2022, TA0/TN), 13 partnerů

THANK YOU FOR YOUR ATTENTION

